

4. Hot Socketing & Power-On Reset

Stratix® II devices offer hot socketing, which is also known as hot plug-in or hot swap, and power sequencing support without the use of any external devices. You can insert or remove a Stratix II board in a system during system operation without causing undesirable effects to the running system bus or the board that was inserted into the system.

The hot socketing feature also removes some of the difficulty when you use Stratix II devices on printed circuit boards (PCBs) that also contain a mixture of 5.0-, 3.3-, 2.5-, 1.8-, 1.5- and 1.2-V devices. With the Stratix II hot socketing feature, you no longer need to ensure a proper power-up sequence for each device on the board.

The Stratix II hot socketing feature provides:

- Board or device insertion and removal without external components or board manipulation
- Support for any power-up sequence
- Non-intrusive I/O buffers to system buses during hot insertion

This chapter also discusses the power-on reset (POR) circuitry in Stratix II devices. The POR circuitry keeps the devices in the reset state until the V_{CC} is within operating range.

Stratix II Hot-Socketing Specifications

Stratix II devices offer hot socketing capability with all three features listed above without any external components or special design requirements. The hot socketing feature in Stratix II devices allows:

- The device can be driven before power-up without any damage to the device itself.
- I/O pins remain tri-stated during power-up. The device does not drive out before or during power-up, thereby affecting other buses in operation.
- Signal pins do not drive the V_{CCIO} , V_{CCPD} , or V_{CCINT} power supplies. External input signals to I/O pins of the device do not internally power the V_{CCIO} or V_{CCINT} power supplies of the device via internal paths within the device.

Devices Can Be Driven Before Power-Up

You can drive signals into the I/O pins, dedicated input pins and dedicated clock pins of Stratix II devices before or during power-up or power-down without damaging the device. Stratix II devices support any power-up or power-down sequence (V_{CCIO} , V_{CCINT} , and V_{CCPD}) in order to simplify system level design.

I/O Pins Remain Tri-States During Power-Up

A device that does not support hot-socketing may interrupt system operation or cause contention by driving out before or during power-up. In a hot socketing situation, Stratix II device's output buffers are turned off during system power-up or power-down. Stratix II device also does not drive out until the device is configured and has attained proper operating conditions.

Signal Pins Do Not Drive the V_{CCIO} , V_{CCINT} or V_{CCPD} Power Supplies

Devices that do not support hot-socketing can short power supplies together when powered-up through the device signal pins. This irregular power-up can damage both the driving and driven devices and can disrupt card power-up.

Stratix II devices do not have a current path from I/O pins, dedicated input pins, or dedicated clock pins to the V_{CCIO} , V_{CCINT} , or V_{CCPD} pins before or during power-up. A Stratix II device may be inserted into (or removed from) a powered-up system board without damaging or interfering with system-board operation. When hot-socketing, Stratix II devices may have a minimal effect on the signal integrity of the backplane.



You can power up or power down the V_{CCIO} , V_{CCINT} , and V_{CCPD} pins in any sequence. The power supply ramp rates can range from 100 μ s to 100 ms. All V_{CC} supplies must power down within 100 ms of each other to prevent I/O pins from driving out. During hot socketing, the I/O pin capacitance is less than 15 pF and the clock pin capacitance is less than 20 pF. Stratix II devices meet the following hot socketing specification.

- The hot socketing DC specification is: $| I_{IOPIN} | < 300 \mu\text{A}$.
- The hot socketing AC specification is: $| I_{IOPIN} | < 8 \text{ mA}$ for 10 ns or less.


I/O Standard	Loading and Termination						Measurement Point
	R_S (Ω)	R_D (Ω)	R_T (Ω)	V_{CCIO} (V)	V_{TT} (V)	C_L (pF)	V_{MEAS} (V)
LVTTL (4)				3.135		0	1.5675
LVCMOS (4)				3.135		0	1.5675
2.5 V (4)				2.375		0	1.1875
1.8 V (4)				1.710		0	0.855
1.5 V (4)				1.425		0	0.7125
PCI (5)				2.970		10	1.485
PCI-X (5)				2.970		10	1.485
SSTL-2 Class I	25		50	2.325	1.123	0	1.1625
SSTL-2 Class II	25		25	2.325	1.123	0	1.1625
SSTL-18 Class I	25		50	1.660	0.790	0	0.83
SSTL-18 Class II	25		25	1.660	0.790	0	0.83
1.8-V HSTL Class I	50		50	1.660	0.790	0	0.83
1.8-V HSTL Class II	25		25	1.660	0.790	0	0.83
1.5-V HSTL Class I	50		50	1.375	0.648	0	0.6875
1.5-V HSTL Class II			25	1.375	0.648	0	0.6875
1.2-V HSTL with OCT	50			1.140		0	0.570
Differential SSTL-2 Class I	50		50	2.325	1.123	0	1.1625
Differential SSTL-2 Class II	25		25	2.325	1.123	0	1.1625
Differential SSTL-18 Class I	50		50	1.660	0.790	0	0.83
Differential SSTL-18 Class II	25		25	1.660	0.790	0	0.83
1.5-V Differential HSTL Class I	50		50	1.375	0.648	0	0.6875
1.5-V Differential HSTL Class II			25	1.375	0.648	0	0.6875
1.8-V Differential HSTL Class I	50		50	1.660	0.790	0	0.83
1.8-V Differential HSTL Class II	25		25	1.660	0.790	0	0.83
LVDS		100		2.325		0	1.1625
HyperTransport		100		2.325		0	1.1625
LVPECL		100		3.135		0	1.5675

Notes to Table 5–34:

- (1) Input measurement point at internal node is $0.5 \times V_{CCINT}$.
- (2) Output measuring point for V_{MEAS} at buffer output is $0.5 \times V_{CCIO}$.
- (3) Input stimulus edge rate is 0 to V_{CC} in 0.2 ns (internal signal) from the driver preceding the I/O buffer.
- (4) Less than 50-mV ripple on V_{CCIO} and V_{CCPD} , $V_{CCINT} = 1.15$ V with less than 30-mV ripple
- (5) $V_{CCPD} = 2.97$ V, less than 50-mV ripple on V_{CCIO} and V_{CCPD} , $V_{CCINT} = 1.15$ V

产品种类:	FPGA - 现场可编程门阵列	<input checked="" type="checkbox"/>
RoHS:	N	
产品:	Cyclone III	<input type="checkbox"/>
系列:	Cyclone III EP3C80	<input type="checkbox"/>
逻辑元件数量:	81264 LE	<input type="checkbox"/>
自适应逻辑模块 - ALM:	-	<input type="checkbox"/>
嵌入式内存:	2.68 Mbit	<input type="checkbox"/>
输入/输出端数量:	429 I/O	<input type="checkbox"/>
工作电源电压:	1.15 V to 1.25 V	<input type="checkbox"/>
最小工作温度:	0 C	<input type="checkbox"/>
最大工作温度:	+ 70 C	<input type="checkbox"/>
安装风格:	SMD/SMT	<input type="checkbox"/>
封装 / 箱体:	FBGA-780	<input type="checkbox"/>
封装:	Tray	<input type="checkbox"/>
商标:	Intel / Altera	
最大工作频率:	315 MHz	
湿度敏感性:	Yes	
逻辑数组块数量——LAB:	5079 LAB	
产品类型:	FPGA - Field Programmable Gate Array	
工厂包装数量:	36	
子类别:	Programmable Logic ICs	
总内存:	2810880 bit	
商标名:	Cyclone III	
零件号别名:	972403	

Document Revision History

芯片详细信息			
Manufacturer Part Number: EP3C80F780C8	Rohs Code:  No	Part Life Cycle Code: Active	Ihs Manufacturer: INTEL CORP
Package Description: 29 X 29 MM, 1 MM PITCH, FBGA-780	Reach Compliance Code: compliant	ECCN Code: 3A991	HTS Code: 8542.39.00.01
Manufacturer: Intel Corporation	Risk Rank: 5.29	Clock Frequency-Max: 472.5 MHz	JESD-30 Code: S-PBGA-B780
JESD-609 Code: e0	Length: 29 mm	Moisture Sensitivity Level: 3	Number of CLBs: 81264
Number of Inputs: 429	Number of Logic Cells: 81264	Number of Outputs: 429	Number of Terminals: 780
Operating Temperature-Max: 85 °C	Organization: 81264 CLBS	Package Body Material: PLASTIC/EPOXY	Package Code: BGA
Package Equivalence Code: BGA780,28X28,40	Package Shape: SQUARE	Package Style: GRID ARRAY	Peak Reflow Temperature (Cel): 220
Programmable Logic Type: FIELD PROGRAMMABLE GATE ARRAY	Qualification Status: Not Qualified	Seated Height-Max: 2.4 mm	Subcategory: Field Programmable Gate Arrays
Supply Voltage-Max: 1.25 V	Supply Voltage-Min: 1.15 V	Supply Voltage-Nom: 1.2 V	Surface Mount: YES
Technology: CMOS	Temperature Grade: OTHER	Terminal Finish: TIN LEAD	Terminal Form: BALL
Terminal Pitch: 1 mm	Terminal Position: BOTTOM	Time@Peak Reflow Temperature- Max (s): 30	Width: 29 mm